



**UNITED STATES DEPARTMENT OF COMMERCE**  
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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.
09/525,802	03/15/00	HIDAKA	I AKM-00301

PATENT GROUP  
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101 FEDERAL STREET  
BOSTON MA 02110

MM92/0103

EXAMINER

CRUZ, L

ART UNIT	PAPER NUMBER
2815	9

2815

DATE MAILED: 01/03/01

Please find below and/or attached an Office communication concerning this application or proceeding.

Commissioner of Patents and Trademarks

<b>Office Action Summary</b>	<b>Application No.</b> 09/525,802	<b>Applicant(s)</b> HIDAKA, ITSUO	
	<b>Examiner</b> Lourdes C. Cruz	<b>Art Unit</b> 2815	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

#### Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 1 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136 (a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).

#### Status

- 1) ☒ Responsive to communication(s) filed on 26 October 2000.
- 2a) ☒ This action is FINAL.                      2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

#### Disposition of Claims

- 4) ☒ Claim(s) 1-18 is/are pending in the application.
- 4a) Of the above claim(s) \_\_\_\_\_ is/are withdrawn from consideration.
- 5) ☐ Claim(s) \_\_\_\_\_ is/are allowed.
- 6) ☒ Claim(s) 1-18 is/are rejected.
- 7) ☐ Claim(s) \_\_\_\_\_ is/are objected to.
- 8) ☐ Claims \_\_\_\_\_ are subject to restriction and/or election requirement.

#### Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on \_\_\_\_\_ is/are objected to by the Examiner.
- 11) ☐ The proposed drawing correction filed on \_\_\_\_\_ is: a) ☐ approved b) ☐ disapproved.
- 12) ☐ The oath or declaration is objected to by the Examiner.

#### Priority under 35 U.S.C. § 119

- 13) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d).
- a) ☐ All b) ☐ Some \* c) ☐ None of the CERTIFIED copies of the priority documents have been:
1. ☐ received.
2. ☐ received in Application No. (Series Code / Serial Number) \_\_\_\_\_.
3. ☐ received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- \* See the attached detailed Office action for a list of the certified copies not received.
- 14) ☐ Acknowledgement is made of a claim for domestic priority under 35 U.S.C. & 119(e).

#### Attachment(s)

- |   |  |
|---|--|
| 15) <input type="checkbox"/> Notice of References Cited (PTO-892)                             | 18) <input type="checkbox"/> Interview Summary (PTO-413) Paper No(s). _____  |
| 16) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948)         | 19) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| 17) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449) Paper No(s) _____ | 20) <input type="checkbox"/> Other:  |

### **DETAILED ACTION**

This Office Action is in response to an Amendment filed October 18, 2000.

#### ***Drawings***

Figures 8 and 9 should be designated by a legend such as --Prior Art-- because only that which is old is illustrated. See MPEP § 608.02(g).

#### ***Claim Rejections - 35 USC § 102***

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1-4 are rejected under 35 U.S.C. 102(b) as being anticipated by Landis (U.S. Patent No. 4673904).

Landis discloses a semiconductor device (See Fig. 8) having multiple wiring layers, comprising: a signal line (84), which is formed in a wiring layer, and to which a signal voltage is applied;

two adjacent lines (80) which are so adjacent to said signal line as not to be connected thereto, and which are formed in a wiring layer where said signal line is formed.

two intersection lines (90,68) which are respectively formed in wiring layers each being present via an insulating layer (70) above or under the wiring layer where said signal line and said adjacent line are formed, and which are formed along a surface area corresponding to an area which is enclosed by said two adjacent lines.

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a plurality of entire-line-area through holes (88,86,74,72) which respectively penetrate through the insulating layers formed between said adjacent lines, and which respectively and electrically connect said two adjacent lines and said two intersection lines wherein said signal line is completely enclosed by said two adjacent lines, said two intersection lines, and said entire-line-area through-holes, which are one of conductors and semiconductors.

Regarding claim 2, Landis discloses the semiconductor device according to claim 1, wherein said two adjacent lines are formed substantially parallel to said signal line.

Claims 5-18 are rejected under 35 U.S.C. 102(b) as being anticipated by Schreiber et al. (U.S. Patent No. 4845311).

With regard to claim 5, Schreiber et al. disclose a semiconductor device (See Fig. 1) having multiple wiring layers, comprising: a plurality of signal lines (60), which is formed not to intersect each other in an identical wiring layer;

two adjacent lines (44,42) which are so formed adjacent onto both sides of said plurality of signal lines as not to be connected thereto, and which are formed in a wiring layer where said plurality of signal lines is formed.

two intersection lines (74,76) which are formed in wiring layers each being present via an insulating layers (82) above or under the wiring layer where said signal line and said adjacent line are formed, and which are formed along a surface area corresponding to an area which is enclosed by said two adjacent lines; and

a plurality of entire-line-area through holes (26,27) which respectively penetrate through the insulating layers formed between said adjacent lines, and which respectively and electrically connect said two adjacent lines and said two intersection lines wherein said signal line is completely enclosed by said two adjacent lines, said two intersection lines, and said entire-line-area through-holes, which are one of conductors and semiconductors.

With regard to claim 8, Schreiber et al. disclose a semiconductor device (See Fig. 1) having multiple wiring layers, comprising: a plurality of signal lines (60), which are formed not to intersect each other in an identical wiring layer;

two first adjacent lines (44,42) which are so formed adjacent onto both sides of said plurality of signal lines as not to be connected thereto, and which are formed in a wiring layer where said plurality of signal lines is formed.

at least one second adjacent line (not labeled) which is formed in the wiring layer where said plurality of signal lines are formed, between said plurality of signal lines so as not to be connected to said plurality of signal lines;

two intersection lines (74,76) which are formed in wiring layers each being present via an insulating layers (82) above or under the wiring layer where said signal line and said adjacent line are formed, and which are formed along a surface area corresponding to an area which is enclosed by said two adjacent lines; and

entire-line-area through holes (26,27) which respectively penetrate through the insulating layers (82) formed between said adjacent lines, and which respectively and electrically connect said two adjacent lines and said two intersection lines wherein said

signal lines are completely enclosed by said two adjacent lines, said two intersection lines, and said entire-line-area through-holes, which are one of conductors and semiconductors.

With regard to claim 10, Schreiber et al. discloses a semiconductor device (See Fig. 1) having multiple wiring layers, comprising: a plurality of signal lines (60), which are formed substantially in parallel to each other in different wiring layers;

a plurality of adjacent lines (44,42) each pair of which are so formed adjacent onto both sides of said plurality of signal lines as not to be connected thereto, and which are formed in a wiring layer where said plurality of signal lines is formed.

two intersection lines (74,76) each of which is formed in a layer under a lowermost wiring layer where plurality of signal lines are formed, and which are formed along a surface area corresponding to an area enclosed by said plurality of adjacent lines formed on the both extreme sides of said plurality of signal lines (See Fig. 1); and

a plurality of first entire-line-area through holes (26,17) which penetrate through an insulating layer (82) arranged between said adjacent lines (See Fig. 1), and which electrically connect said adjacent lines with said two intersection lines; and

a plurality of second entire-line-area through holes (27,19) which penetrate through an insulating layer arranged between said adjacent lines, along the entire areas of said adjacent lines, and which electrically connects said adjacent lines with each other (See Fig. 1) wherein said signal lines are completely enclosed by said two adjacent lines, said two intersection lines, and said entire-line-area through-holes, which are one of conductors and semiconductors.

With regard to claim 13, Schreiber et al. disclose a semiconductor device (See Fig. 1) having multiple wiring layers, comprising: a plurality of signal lines (60), which are formed in different wiring layers, and to which signal voltages are applied;

a plurality of adjacent lines (40,46) each pair of which are formed either in a lowermost or uppermost wiring layer, of the wiring layers where said plurality of signal lines (60) are formed, respectively adjacent onto both sides of one of said plurality of signal lines which is formed in an identical layer, thereby not to be connected to the one of said plurality of signal lines;

two first intersection lines (Not labeled) each of which is formed either in a wiring layer under a lowermost wiring layer of said signal lines, or in a wiring wiring layer above the uppermost wiring layer of said signal lines, and each of which is formed along a surface area corresponding to an area enclosed by said pair of adjacent lines formed on the both sides of a corresponding one of said plurality of signal lines formed either in the lowermost or uppermost wiring layer of said signal lines (See Fig. 1);

a second intersection line (42) which is formed in a wiring layer formed between said wiring layers of said signal lines, and which is formed along a surface area corresponding to at least one area enclosed by said pair of adjacent lines;

a plurality of first entire-line-area through holes (81,85) which penetrate through insulating layers between said adjacent lines (See Fig. 1) and said first intersection lines, along entire areas of said adjacent lines, thereby electrically connecting said adjacent lines with said two first intersection lines; and

a plurality of second entire-line-area through holes (17,27) which penetrate through insulating layers (82) formed between said adjacent lines and said second intersection lines, along the entire areas of said adjacent lines, thereby electrically connecting said adjacent lines with said intersection line (See Fig. 1) wherein said signal lines are completely enclosed by said two adjacent lines, said two intersection lines, and said entire-line-area through-holes, which are one of conductors and semiconductors.

Regarding claim 16, Schreiber et al. disclose the semiconductor device according to claim 13, wherein said signal lines are formed in different layers which are adjacent to each other intersect each other.

Regarding claims 3-9,11,12 and 14,15,17 and 18 see In re Pearson 181 USPQ 641 (CCPA) which makes clear that terms setting forth an intended use for, or a property inherent in, an otherwise old composition do not differentiate claimed composition from those known to prior art. See also, In re Swinehart [169 USPQ 226] (CCPA 1971) which makes clear that mere recitation of a newly discovered function or property, inherently possessed by things in prior art, does not cause claim drawn to those things to distinguish over prior art.

Regarding amended claims 17 and 18 Schreiber discloses a signal line 46 completely enclosed by adjacent lines 40, intersection lines 104,105 and through holes 27 penetrating through insulating layers 82 (See Fig. 1).



***Response to Arguments***

Applicant's arguments filed October 26, 2000 have been fully considered but they are not persuasive. The amendment filed has been fully considered but fails to be patentably distinct over the references cited. Landis discloses a semiconductor device with multiple wiring layers wherein a signal line is completely enclosed by two adjacent lines, two intersection lines, and entire line area through holes, which are one of conductors or semiconductors (metallic strips). Regarding arguments concerning claims 3 and 4, please see rejection based on a disclosed Intended Use as set forth in this Office Action, as well as in the previous one. Same Applies to all other claims being rejected for disclosing such limitations.

Regarding claims 5-18, the claims as amended fail to structurally differentiate the claimed invention from that which is disclosed by '311. Schreiber discloses a semiconductor device with multiple wiring layers wherein a signal line is completely enclosed by two adjacent lines, two intersection lines, and entire line area through holes, which are one of conductors or semiconductors as set forth in the Office Action. Schreiber clearly anticipates the invention as claimed, therefore Applicant's arguments regarding '311's failure to disclose/suggest the claimed invention are found not persuasive. The examiner has considered all the claims as amended, however withdrawal of rejections is not granted base on the grounds set above, and objections to the drawings have not been overcome.

***Conclusion***

**THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Kobayashi (U.S. Patent 5357138) discloses a coaxial wiring pattern structure in a multi layered wiring board. Tomie (U.S. Patent 6043556) discloses a high frequency input/output package. Tsuji (U.S. Patent No. 5491352) discloses a semiconductor device having peripheral metal wiring. Yamamoto et al. (U.S. Patent No. 4626889) disclose a stacked differentially driven transmission line on integrated circuit. Hesson et al. (U.S. Patent No. 5136357) disclose a low-noise, area efficient line structure. Cronin et al. (U.S. Patent No. 4776087) disclose a VLSI coaxial wiring structure. Latham, IV et al. (U.S. Patent No. 5811882) disclose on-chip shielding coaxial conductors.

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to Lourdes C. Cruz whose telephone number is 707-306-5691. The examiner can normally be reached on M-F 8:00- 4:30.

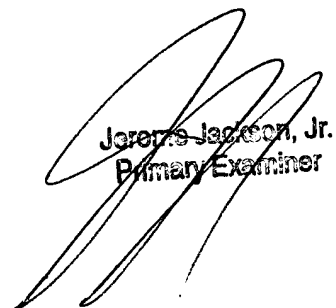
If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie Lee can be reached on 703-308-1690. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-308-7722 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

Lourdes C. Cruz  
Examiner  
Art Unit 2815



Lourdes Cruz  
December 29, 2000



Jerome Jackson, Jr.  
Primary Examiner